

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L5	195470	(metal\$4 NEAR3 oxide\$4 NEAR3 semi\$1conduct\$4) OR MOS OR MOS\$1FET OR \$4FET	US-PGPUB; USPAT	OR	OFF	2006/05/12 18:19
L6	18495	L5 AND (dop\$4 NEAR10 poly\$1silicon\$4)	US-PGPUB; USPAT	OR	OFF	2006/05/12 18:19
L7	9808	L6 AND ((n\$1type OR n\$2dop\$4) AND (p\$1type OR p\$2dop\$4))	US-PGPUB; USPAT	OR	OFF	2006/05/12 18:19
L8	552	L7 AND (etch\$4 NEAR20 uniform\$4)	US-PGPUB; USPAT	OR	OFF	2006/05/12 16:25
L9	231	L7 AND (etch\$4 NEAR20 (rate\$4 OR uniform\$4 OR profil\$4) NEAR20 dop\$4)	US-PGPUB; USPAT	OR	OFF	2006/05/12 17:07
L10	54	L9 AND (hard\$1mask\$4 OR hardmask\$4 OR (hard\$4 ADJ mask\$4))	US-PGPUB; USPAT	OR	OFF	2006/05/12 16:25
L13	12411	L6 AND ((n\$1type OR n\$2dop\$4) OR (p\$1type OR p\$2dop\$4))	US-PGPUB; USPAT	OR	OFF	2006/05/12 18:21
L14	1696	L13 AND (un\$1dop\$4 NEAR20 poly\$1silicon\$4)	US-PGPUB; USPAT	OR	OFF	2006/05/12 16:55
L15	77	L14 AND (etch\$4 NEAR20 (rate\$4 OR uniform\$4 OR profil\$4) NEAR20 dop\$4)	US-PGPUB; USPAT	OR	OFF	2006/05/12 16:55
L17	135	L14 AND (etch\$4 NEAR20 rate\$4 NEAR20 poly\$1silicon\$4)	US-PGPUB; USPAT	OR	OFF	2006/05/12 18:22
L18	26	L14 AND (etch\$4 NEAR20 rate\$4 NEAR20 poly\$1silicon\$4)	US-PGPUB	OR	OFF	2006/05/12 18:16
L19	166758	(metal\$4 NEAR3 oxide\$4 NEAR3 semi\$1conduct\$4) OR MOS OR MOS\$1FET OR \$4FET	EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/12 18:19
L20	1535	L19 AND (dop\$4 NEAR10 poly\$1silicon\$4)	EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/12 18:19
L21	363	L20 AND ((n\$1type OR n\$2dop\$4) OR (p\$1type OR p\$2dop\$4))	EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/12 18:21
L22	5	L21 AND (etch\$4 NEAR20 rate\$4 NEAR20 poly\$1silicon\$4)	EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/12 18:22
L23	1	("20040266200").PN.	US-PGPUB	OR	OFF	2006/05/12 18:23
L24	5093	((216/58,62,79) or (438/369,659,706,710,719,766,924)).CCLS.	US-PGPUB; USPAT	OR	OFF	2006/05/12 18:38
L25	10	L24 AND L17	US-PGPUB; USPAT	OR	OFF	2006/05/12 18:38